CMOS Digital Integrated Circuits Silicon Monolithic

TC7MP3125FK

1. Functional Description

Low-Voltage, Low-Power 2-Bit × 2 Dual-Supply Bus Transceiver

2. General

The TC7MP3215FK is an advanced high-speed CMOS 4-bit dual supply voltage interface bus transceiver fabricated with silicon gate CMOS technology.

All inputs and outputs have tolerant function, and can be applied up to 3.6 V at power down mode.

The input consists of two same 2-bit configuration and it can be used as dual 2-bit configurations or single 4-bit configuration.

When the DIR input that changes transmission direction is H level, A-bus works as input and B-bus works as output, and when the DIR is L level, A-bus works as output and B-bus works as input.

When the Enable input \overline{OE} is H level, both A-bus and B-bus become to floating state (high-impedance).

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features (Note)

(1) Operating voltage: 1.2 V and 1.8 V / 1.2 V and 2.5 V / 1.2 V and 3.3 V / 1.5 V and 2.5 V

1.5 V and 3.3 V / 1.8 V and 2.5 V / 1.8 V and 3.3 V / 2.5 V and 3.3 V bidirectional interface

(2) High-speed operation: $t_{pd} = 6.8 \text{ ns} (\text{max}) (V_{CCA} = 2.5 \pm 0.2 \text{ V}, V_{CCB} = 3.3 \pm 0.3 \text{ V})$

$$t_{pd} = 8.9 \text{ ns} (\text{max}) (V_{CCA} = 1.8 \pm 0.15 \text{ V}, V_{CCB} = 3.3 \pm 0.3 \text{ V})$$

 $t_{pd} = 10.3 \text{ ns} (\text{max}) (V_{CCA} = 1.5 \pm 0.1 \text{ V}, V_{CCB} = 3.3 \pm 0.3 \text{ V})$
 $t_{pd} = 61 \text{ ns} (\text{max}) (V_{CCA} = 1.2 \pm 0.1 \text{ V}, V_{CCB} = 3.3 \pm 0.3 \text{ V})$
 $t_{rd} = 95 \text{ ns} (\text{max}) (V_{CCA} = 1.8 \pm 0.15 \text{ V}, V_{CCB} = 2.5 \pm 0.2 \text{ V})$

$$t_{nd} = 10.8 \text{ ns} (\text{max}) (V_{CCA} = 1.5 \pm 0.1 \text{ V}, V_{CCB} = 2.5 \pm 0.2 \text{ V})$$

$$t_{nd} = 60 \text{ ns} (max) (V_{CCA} = 1.2 \pm 0.1 \text{ V}, V_{CCB} = 2.5 \pm 0.2 \text{ V})$$

$$t_{pd}$$
 = 58 ns (max) (V_{CCA} = 1.2 ± 0.1 V, V_{CCB} = 1.8 ± 0.15 V)

(3) Output current:
$$|I_{OH}|/I_{OL} = 12 \text{ mA} \text{ (min)} (V_{CC} = 3.0 \text{ V})$$

$$|I_{OH}|/I_{OL} = 9 \text{ mA (min)} (V_{CC} = 2.3 \text{ V})$$

$$|I_{OH}|/I_{OL} = 3 \text{ mA} \text{ (min)} (V_{CC} = 1.65 \text{ V})$$

$$|I_{OH}|/I_{OL} = 1 \text{ mA (min)} (V_{CC} = 1.4 \text{ V})$$

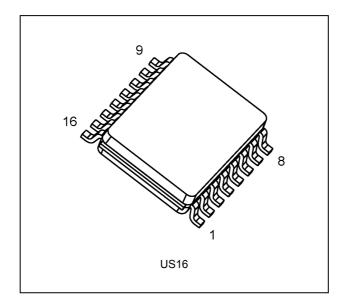
- (4) Latch-up performance: $\geq \pm 300 \text{ mA}$
- (5) ESD performance: $MM \ge \pm 200 \text{ V}$, $HBM \ge \pm 2000 \text{ V}$
- (6) Ultra-small package: VSSOP (US16)
- (7) Low power dissipation: By using the new circuit, the power consumption is reduced significantly when $\overline{OE} = "H"$.

Suitable for battery-driven applications such as PDAs and cellular phones.

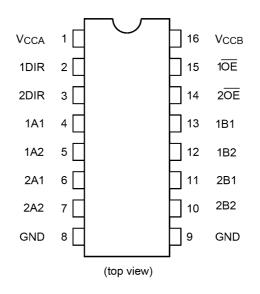
- (8) Floating of A-bus and B-bus is permitted (when $\overline{OE} = "H"$).
- (9) 3.6 V tolerance and power-down protection are provided to all inputs and outputs.

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

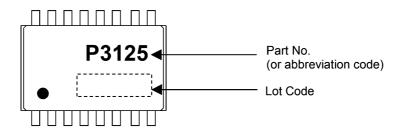
4. Packaging



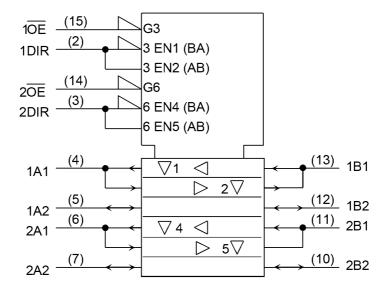
5. Pin Assignment



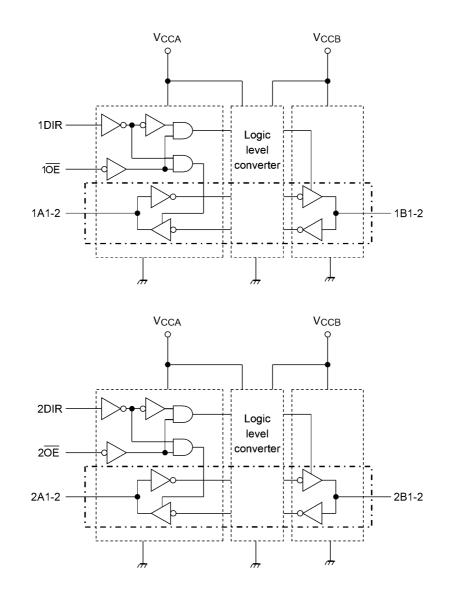
6. Marking



7. IEC Logic Symbol



8. Block Diagram



9. Truth Table

Input 10E	Input 1DIR	Function Bus 1A1-1A2	Function Bus 1B1-1B2	Outputs
L	L	Output	Input	A = B
L	Н	Input	Output	B = A
Н	Х	Z	Z	Z
In <u>put</u> 20E	Input 2DIR	Function Bus 2A1-2A2	Function Bus 2B1-2B2	Outputs
Input 2OE L				Outputs A = B
2OE		Bus 2A1-2A2	Bus 2B1-2B2	•

X: Don't care

Z: High impedance

10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CCA}	(Note 1)	-0.5 to 4.6	V
	V _{CCB}		-0.5 to 4.6	7
Input voltage (DIR, OE)	V _{IN}		-0.5 to 4.6	V
Bus I/O voltage	V _{I/OA}	(Note 2)	-0.5 to 4.6	V
		(Note 3)	-0.5 to V _{CCA} + 0.5	7
	V _{I/OB}	(Note 2)	-0.5 to 4.6	7
		(Note 3)	-0.5 to V _{CCB} + 0.5	
Input diode current	I _{IK}		-50	mA
I/O diode current	I _{I/OK}	(Note 4)	±50	mA
Output current	I _{OUTA}		±25	mA
	I _{OUTB}		±25	7
V _{CC} /ground current per supply pin	I _{CCA}		±50	mA
	I _{CCB}	1	±50	
Power dissipation	PD		180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Don't supply a voltage to V_{CCB} pin when V_{CCA} is in the OFF state.

Note 2: Output in OFF state.

Note 3: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 4: V_{OUT} < GND, V_{OUT} > V_{CC}

11. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CCA}	(Note 1)	—	1.1 to 2.7	V
	V _{CCB}			1.65 to 3.6	
Input voltage(DIR, OE)	V _{IN}		—	0 to 3.6	V
Bus I/O voltage	V _{I/OA}	(Note 2)	—	0 to 3.6	V
		(Note 3)		0 to V _{CCA}	
	V _{I/OB}	(Note 2)		0 to 3.6	
		(Note 3)		0 to V _{CCB}	
Output current	I _{OUTA}		V _{CCA} = 2.3 to 2.7 V	±9	mA
			V _{CCA} = 1.65 to 1.95 V	±3	7
			V _{CCA} = 1.4 to 1.6 V	±1	
	I _{OUTB}		V _{CCB} = 3.0 to 3.6 V	±12	
			V _{CCB} = 2.3 to 2.7 V	±9	7
			V _{CCB} = 1.65 to 1.95 V	±3	7
Operating temperature	T _{opr}		_	-40 to 85	°C
Input rise and fall times	dt/dv		V_{IN} = 0.8 to 2.0 V, V_{CCA} = 2.5 V, V_{CCB} = 3.0 V	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND.

Note 1: Don't use at $V_{CCA} > V_{CCB}$.

Note 2: Output in OFF state.

Note 3: High (H) or Low (L) state.

12. Electrical Characteristics

12.1. DC Characteristics

12.1.1. 2.3 V \leq V_{CCA} \leq 2.7 V, 2.7 V < V_{CCB} \leq 3.6 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Condition	ı	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
High-level input voltage	V_{IHA}	DIR, OE, An		2.3 to 2.7	2.7 to 3.6	1.6	_	V
	V_{IHB}	Bn	3n		2.7 to 3.6	2.0		
Low-level input voltage	V_{ILA}	DIR, OE, An		2.3 to 2.7	2.7 to 3.6		0.7	V
	V_{ILB}	Bn		2.3 to 2.7	2.7 to 3.6	_	0.8	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	2.3 to 2.7	2.7 to 3.6	V _{CCA} -0.2	_	V
			I _{OHA} = -9 mA	2.3	2.7 to 3.6	1.7		
	V _{OHB}		I _{OHB} = -100 μA	2.3 to 2.7	2.7 to 3.6	V _{CCB} -0.2	—	
			I _{OHB} = -12 mA	2.3 to 2.7	3.0	2.2	_	
Low-level output voltage	V_{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	2.3 to 2.7	2.7 to 3.6	_	0.2	V
			I _{OLA} = 9 mA	2.3	2.7 to 3.6	_	0.6	
	V_{OLB}		I _{OLB} = 100 μA	2.3 to 2.7	2.7 to 3.6	_	0.2	
			I _{OLB} = 12 mA	2.3 to 2.7	3.0		0.55	
3-state output OFF-state leakage current	I _{OZA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7	2.7 to 3.6		±2.0	μA
	I _{OZB}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		2.3 to 2.7	2.7 to 3.6	_	±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V		2.3 to 2.7	2.7 to 3.6	_	±1.0	μA
Power-off leakage current	I _{OFF1}	V_{IN} , V_{OUT} = 0 to 3.6 V		0	0		2.0	μA
	I _{OFF2}	$\overline{OE} = V_{CCA}$		2.3 to 2.7	0		2.0	
	I _{OFF3}	V_{IN} , V_{OUT} = 0 to 3.6 V		2.3 to 2.7	Open		2.0	
Quiescent supply current	I _{CCA}	V _{INA} = V _{CCA} or GND V _{INB} = V _{CCB} or GND		2.3 to 2.7	2.7 to 3.6		2.0	μA
	I _{CCB}	V _{INA} = V _{CCA} or GND V _{INB} = V _{CCB} or GND		2.3 to 2.7	2.7 to 3.6	_	2.0	
	I _{CCA}	$V_{CCA} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		2.3 to 2.7	2.7 to 3.6		±2.0	
	I _{CCB}	$V_{CCB} \leq (V_{IN}, V_{OUT}) \leq 3.6 \ V$		2.3 to 2.7	2.7 to 3.6		±2.0	
	I _{CCTB}	V _{INB} = V _{CCB} - 0.6 V per input		2.3 to 2.7	2.7 to 3.6		750.0	



12.1.2. 1.65 V \leq V_{CCA} < 2.3 V, 2.7 V < V_{CCB} \leq 3.6 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Conditior	I	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
High-level input voltage	V _{IHA}	DIR, OE, An		1.65 to 2.3	2.7 to 3.6	0.65× V _{CCA}	—	V
	V_{IHB}	Bn		1.65 to 2.3	2.7 to 3.6	2.0		
Low-level input voltage	V _{ILA}	DIR, OE, An		1.65 to 2.3	2.7 to 3.6		0.35× V _{CCA}	V
	V_{ILB}	Bn		1.65 to 2.3	2.7 to 3.6	_	0.8	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	1.65 to 2.3	2.7 to 3.6	V _{CCA} -0.2	—	V
			I _{OHA} = -3 mA	1.65	2.7 to 3.6	1.25	—	
	V _{OHB}		I _{OHB} = -100 μA	1.65 to 2.3	2.7 to 3.6	V _{CCB} -0.2	—	
			I _{OHB} = -12 mA	1.65 to 2.3	3.0	2.2		
Low-level output voltage	V _{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.65 to 2.3	2.7 to 3.6	_	0.2	V
			I _{OLA} = 3 mA	1.65	2.7 to 3.6	—	0.3	
	V _{OLB}		I _{OLB} = 100 μA	1.65 to 2.3	2.7 to 3.6	_	0.2	
			I _{OLB} = 12 mA	1.65 to 2.3	3.0	_	0.55	
3-state output OFF-state leakage current	I _{OZA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.65 to 2.3	2.7 to 3.6	_	±2.0	μΑ
	I _{OZB}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.65 to 2.3	2.7 to 3.6		±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V		1.65 to 2.3	2.7 to 3.6	_	±1.0	μΑ
Power-off leakage current	I _{OFF1}	V _{IN} , V _{OUT} = 0 to 3.6 V	·	0	0	_	2.0	μA
	I _{OFF2}	OE = V _{CCA}		1.65 to 2.3	0	_	2.0	
	I _{OFF3}	V_{IN} , V_{OUT} = 0 to 3.6 V		1.65 to 2.3	Open	_	2.0	
Quiescent supply current	I _{CCA}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.65 to 2.3	2.7 to 3.6		2.0	μA
	I _{CCB}	V _{INA} = V _{CCA} or GND V _{INB} = V _{CCB} or GND		1.65 to 2.3	2.7 to 3.6		2.0	
	I _{CCA}	$V_{CCA} \leq (V_{IN}, V_{OUT}) \leq 3.6 \; V$		1.65 to 2.3	2.7 to 3.6	_	±2.0	
	I _{CCB}	$V_{CCB} \leq (V_{IN}, V_{OUT}) \leq 3.6 \ V$		1.65 to 2.3	2.7 to 3.6		±2.0	
	I _{CCTB}	V _{INB} = V _{CCB} - 0.6 V per input		1.65 to 2.3	2.7 to 3.6		750.0	



12.1.3. 1.4 V \leq V_{CCA} < 1.65 V, 2.7 V < V_{CCB} \leq 3.6 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Conditior	1	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
High-level input voltage	V _{IHA}	DIR, OE, An		1.4 to 1.65	2.7 to 3.6	0.65× V _{CCA}	—	V
	V_{IHB}	Bn		1.4 to 1.65	2.7 to 3.6	2.0	—	
Low-level input voltage	V _{ILA}	DIR, OE, An		1.4 to 1.65	2.7 to 3.6		0.30× V _{CCA}	V
	V_{ILB}	Bn		1.4 to 1.65	2.7 to 3.6	_	0.8	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	1.4 to 1.65	2.7 to 3.6	V _{CCA} -0.2	_	V
			I _{OHA} = -1 mA	1.4	2.7 to 3.6	1.05		
	V _{OHB}		I _{OHB} = -100 μA	1.4 to 1.65	2.7 to 3.6	V _{CCB} -0.2	_	
			I _{OHB} = -12 mA	1.4 to 1.65	3.0	2.2	_	
Low-level output voltage	V_{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.4 to 1.65	2.7 to 3.6	—	0.2	V
			I _{OLA} = 1 mA	1.4	2.7 to 3.6	—	0.35	
	V_{OLB}		I _{OLB} = 100 μA	1.4 to 1.65	2.7 to 3.6	_	0.2	
			I _{OLB} = 12 mA	1.4 to 1.65	3.0	_	0.55	
3-state output OFF-state leakage current	I _{OZA}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.4 to 1.65	2.7 to 3.6	_	±2.0	μA
	I _{OZB}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.4 to 1.65	2.7 to 3.6		±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V		1.4 to 1.65	2.7 to 3.6	_	±1.0	μA
Power-off leakage current	I _{OFF1}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	0	_	2.0	μA
	I _{OFF2}	$\overline{OE} = V_{CCA}$	·	1.4 to 1.65	0	_	2.0	
	I _{OFF3}	V _{IN} , V _{OUT} = 0 to 3.6 V		1.4 to 1.65	Open	_	2.0	
Quiescent supply current	I _{CCA}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.4 to 1.65	2.7 to 3.6		2.0	μA
	I _{CCB}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.4 to 1.65	2.7 to 3.6	_	2.0	
	I _{CCA}	$V_{CCA} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		1.4 to 1.65	2.7 to 3.6		±2.0	
	I _{CCB}	$V_{CCB} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		1.4 to 1.65	2.7 to 3.6		±2.0	
	I _{CCTB}	V _{INB} = V _{CCB} - 0.6 V per input		1.4 to 1.65	2.7 to 3.6		750.0	



12.1.4. 1.1 V \leq V_{CCA} < 1.4 V, 2.7 V < V_{CCB} \leq 3.6 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Conditior	ı	V _{CCA} (V)	V _{CCB} (V)	Min	Мах	Unit
High-level input voltage	V _{IHA}	DIR, OE, An		1.1 to 1.4	2.7 to 3.6	0.65× V _{CCA}	—	V
	V _{IHB}	Bn		1.1 to 1.4	2.7 to 3.6	2.0		
Low-level input voltage	V _{ILA}	DIR, OE, An		1.1 to 1.4	2.7 to 3.6		0.30× V _{CCA}	V
	V _{ILB}	Bn		1.1 to 1.4	2.7 to 3.6	_	0.8	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	1.1 to 1.4	2.7 to 3.6	V _{CCA} -0.2	—	V
	V _{OHB}		I _{OHB} = -100 μA	1.1 to 1.4	2.7 to 3.6	V _{CCB} -0.2	—	
			I _{OHB} = -12 mA	1.1 to 1.4	3.0	2.2		
Low-level output voltage	V _{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.1 to 1.4	2.7 to 3.6	_	0.2	V
	V _{OLB}		I _{OLB} = 100 μA	1.1 to 1.4	2.7 to 3.6	—	0.2	
			I _{OLB} = 12 mA	1.1 to 1.4	3.0	_	0.55	
3-state output OFF-state leakage current	I _{OZA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.1 to 1.4	2.7 to 3.6		±2.0	μΑ
	I _{OZB}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.1 to 1.4	2.7 to 3.6		±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V		1.1 to 1.4	2.7 to 3.6		±1.0	μA
Power-off leakage current	I _{OFF1}	V_{IN} , V_{OUT} = 0 to 3.6 V		0	0		2.0	μA
	I _{OFF2}	OE = V _{CCA}		1.1 to 1.4	0	_	2.0	
	I _{OFF3}	V _{IN} , V _{OUT} = 0 to 3.6 V		1.1 to 1.4	Open	—	2.0	
Quiescent supply current	I _{CCA}	V _{INA} = V _{CCA} or GND V _{INB} = V _{CCB} or GND		1.1 to 1.4	2.7 to 3.6	_	2.0	μA
	I _{CCB}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.1 to 1.4	2.7 to 3.6	_	2.0	
	I _{CCA}	$V_{CCA} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		1.1 to 1.4	2.7 to 3.6	_	±2.0	
	I _{CCB}	$V_{CCB} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		1.1 to 1.4	2.7 to 3.6		±2.0	
	I _{CCTB}	V _{INB} = V _{CCB} - 0.6 V per input		1.1 to 1.4	2.7 to 3.6	_	750.0	



12.1.5. 1.65 V \leq V_{CCA} < 2.3 V, 2.3 V \leq V_{CCB} \leq 2.7 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Condition	I	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
High-level input voltage	V _{IHA}	DIR, OE, An		1.65 to 2.3	2.3 to 2.7	0.65× V _{CCA}	—	V
	V_{IHB}	Bn		1.65 to 2.3	2.3 to 2.7	1.6	_	
Low-level input voltage	V _{ILA}	DIR, OE, An		1.65 to 2.3	2.3 to 2.7	_	0.35× V _{CCA}	V
	V _{ILB}	Bn		1.65 to 2.3	2.3 to 2.7	_	0.7	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	1.65 to 2.3	2.3 to 2.7	V _{CCA} -0.2	—	V
			I _{OHA} = -3 mA	1.65	2.3 to 2.7	1.25	_	
	V _{OHB}		I _{OHB} = -100 μA	1.65 to 2.3	2.3 to 2.7	V _{CCB} -0.2	_	
			I _{OHB} = -9 mA	1.65 to 2.3	2.3	1.7	_	
Low-level output voltage	V _{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.65 to 2.3	2.3 to 2.7	_	0.2	V
			I _{OLA} = 3 mA	1.65	2.3 to 2.7	_	0.3	
	V_{OLB}		I _{OLB} = 100 μA	1.65 to 2.3	2.3 to 2.7		0.2	
			I _{OLB} = 9 mA	1.65 to 2.3	2.3		0.6	
3-state output OFF-state leakage current	I _{OZA}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.65 to 2.3	2.3 to 2.7		±2.0	μA
	I _{OZB}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.65 to 2.3	2.3 to 2.7		±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V		1.65 to 2.3	2.3 to 2.7	_	±1.0	μA
Power-off leakage current	I _{OFF1}	V_{IN} , V_{OUT} = 0 to 3.6 V		0	0		2.0	μA
	I _{OFF2}	$\overline{OE} = V_{CCA}$		1.65 to 2.3	0		2.0	
	I _{OFF3}	V_{IN} , V_{OUT} = 0 to 3.6 V		1.65 to 2.3	Open	_	2.0	
Quiescent supply current	I _{CCA}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.65 to 2.3	2.3 to 2.7		2.0	μA
	I _{CCB}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.65 to 2.3	2.3 to 2.7		2.0	
	I _{CCA}	$V_{CCA} \leq (V_{IN}, V_{OUT}) \leq 3.6 \ V$		1.65 to 2.3	2.3 to 2.7	_	±2.0	
	I _{CCB}	$V_{CCB} \leq (V_{IN}, V_{OUT}) \leq 3.6 \ V$		1.65 to 2.3	2.3 to 2.7	_	±2.0	



12.1.6. 1.4 V \leq V_{CCA} < 1.65 V, 2.3 V \leq V_{CCB} \leq 2.7 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Condition	I	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
High-level input voltage	V _{IHA}	DIR, OE, An		1.4 to 1.65	2.3 to 2.7	0.65× V _{CCA}	—	V
	V _{IHB}	3n		1.4 to 1.65	2.3 to 2.7	1.6	_	
Low-level input voltage	V _{ILA}	DIR, OE, An		1.4 to 1.65	2.3 to 2.7	_	0.30× V _{CCA}	V
	V _{ILB}	Bn		1.4 to 1.65	2.3 to 2.7	_	0.7	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	1.4 to 1.65	2.3 to 2.7	V _{CCA} -0.2	—	V
			I _{OHA} = -1 mA	1.4	2.3 to 2.7	1.05	_	
	V _{OHB}		I _{OHB} = -100 μA	1.4 to 1.65	2.3 to 2.7	V _{CCB} -0.2	—	
			I _{OHB} = -9 mA	1.4 to 1.65	2.3	1.7	_	
Low-level output voltage	V _{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.4 to 1.65	2.3 to 2.7		0.2	V
			I _{OLA} = 1 mA	1.4	2.3 to 2.7	_	0.35	
	V _{OLB}		I _{OLB} = 100 μA	1.4 to 1.65	2.3 to 2.7		0.2	
			I _{OLB} = 9 mA	1.4 to 1.65	2.3		0.6	
3-state output OFF-state leakage current	I _{OZA}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.4 to 1.65	2.3 to 2.7		±2.0	μA
	I _{OZB}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.4 to 1.65	2.3 to 2.7	_	±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V		1.4 to 1.65	2.3 to 2.7	_	±1.0	μA
Power-off leakage current	I _{OFF1}	V_{IN} , V_{OUT} = 0 to 3.6 V		0	0		2.0	μA
	I _{OFF2}	$\overline{OE} = V_{CCA}$		1.4 to 1.65	0		2.0	
	I _{OFF3}	V_{IN} , V_{OUT} = 0 to 3.6 V		1.4 to 1.65	Open	_	2.0	
Quiescent supply current	I _{CCA}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.4 to 1.65	2.3 to 2.7	_	2.0	μA
	I _{CCB}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.4 to 1.65	2.3 to 2.7		2.0	
	I _{CCA}	$V_{CCA} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		1.4 to 1.65	2.3 to 2.7		±2.0	
	I _{CCB}	$V_{CCB} \leq (V_{IN}, V_{OUT}) \leq 3.6 V$		1.4 to 1.65	2.3 to 2.7		±2.0	



12.1.7. 1.1 V \leq V_{CCA} < 1.4 V, 2.3 V \leq V_{CCB} \leq 2.7 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Conditior	ı	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
High-level input voltage	V _{IHA}	DIR, OE, An		1.1 to 1.4	2.3 to 2.7	0.65× V _{CCA}	—	V
	V _{IHB}	Bn	3n		2.3 to 2.7	1.6	—	
Low-level input voltage	V _{ILA}	DIR, OE, An		1.1 to 1.4	2.3 to 2.7		0.30× V _{CCA}	V
	V _{ILB}	Bn		1.1 to 1.4	2.3 to 2.7	—	0.7	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	1.1 to 1.4	2.3 to 2.7	V _{CCA} -0.2	—	V
	V _{OHB}		I _{OHB} = -100 μA	1.1 to 1.4	2.3 to 2.7	V _{CCB} -0.2	—	
			I _{OHB} = -9 mA	1.1 to 1.4	2.3	1.7		
Low-level output voltage	V_{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.1 to 1.4	2.3 to 2.7		0.2	V
	V_{OLB}		I _{OLB} = 100 μA	1.1 to 1.4	2.3 to 2.7		0.2	
			I _{OLB} = 9 mA	1.1 to 1.4	2.3		0.6	
3-state output OFF-state leakage current	I _{OZA}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.1 to 1.4	2.3 to 2.7		±2.0	μA
	I _{OZB}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.1 to 1.4	2.3 to 2.7		±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V		1.1 to 1.4	2.3 to 2.7		±1.0	μA
Power-off leakage current	I _{OFF1}	V_{IN} , V_{OUT} = 0 to 3.6 V		0	0		2.0	μA
	I _{OFF2}	OE = V _{CCA}		1.1 to 1.4	0		2.0	
	I _{OFF3}	V_{IN} , V_{OUT} = 0 to 3.6 V		1.1 to 1.4	Open		2.0	
Quiescent supply current	I _{CCA}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.1 to 1.4	2.3 to 2.7		2.0	μA
	I _{CCB}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.1 to 1.4	2.3 to 2.7		2.0	
	I _{CCA}	$V_{CCA} \leq (V_{IN}, V_{OUT}) \leq 3.6 \ V$		1.1 to 1.4	2.3 to 2.7	_	±2.0	
	I _{CCB}	$V_{CCB} \leq (V_{IN}, V_{OUT}) \leq 3.6 \ V$		1.1 to 1.4	2.3 to 2.7		±2.0	



12.1.8. 1.1 V \leq V_{CCA} < 1.4 V, 1.65 V \leq V_{CCB} < 2.3 V (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Sym- bol	Test Conditio	n	V _{CCA} (V)	V _{CCB} (V)	Min	Max	Unit
High-level input voltage	V _{IHA}	DIR, OE, An		1.1 to 1.4	1.65 to 2.3	0.65× V _{CCA}	—	V
	V _{IHB}	Bn	3n		1.65 to 2.3	0.65× V _{CCB}	—	
Low-level input voltage	V _{ILA}	DIR, OE, An		1.1 to 1.4	1.65 to 2.3	_	0.30× V _{CCA}	V
	V _{ILB}	Bn		1.1 to 1.4	1.65 to 2.3	—	0.35× V _{CCB}	
High-level output voltage	V _{OHA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OHA} = -100 μA	1.1 to 1.4	1.65 to 2.3	V _{CCA} -0.2	—	V
	V _{OHB}		I _{OHB} = -100 μA	1.1 to 1.4	1.65 to 2.3	V _{CCB} -0.2	—	
			I _{ОНВ} = -3 mA	1.1 to 1.4	1.65	1.25	_	
Low-level output voltage	V _{OLA}	V _{IN} = V _{IH} or V _{IL}	I _{OLA} = 100 μA	1.1 to 1.4	1.65 to 2.3	_	0.2	V
	V_{OLB}		I _{OLB} = 100 μA	1.1 to 1.4	1.65 to 2.3	_	0.2	
			I _{OLB} = 3 mA	1.1 to 1.4	1.65	_	0.3	
3-state output OFF-state leakage current	I _{OZA}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.1 to 1.4	1.65 to 2.3	—	±2.0	μA
	I _{OZB}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.1 to 1.4	1.65 to 2.3	—	±2.0	
Input leakage current	I _{IN}	V_{IN} (DIR, \overline{OE}) = 0 to 3.6 V	,	1.1 to 1.4	1.65 to 2.3	_	±1.0	μΑ
Power-off leakage current	I _{OFF1}	V_{IN} , V_{OUT} = 0 to 3.6 V		0	0	_	2.0	μA
	I _{OFF2}	OE = V _{CCA}		1.1 to 1.4	0	_	2.0	
	I _{OFF3}	V _{IN} , V _{OUT} = 0 to 3.6 V		1.1 to 1.4	Open	_	2.0	
Quiescent supply current	I _{CCA}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.1 to 1.4	1.65 to 2.3	—	2.0	μA
	I _{CCB}	$V_{INA} = V_{CCA}$ or GND $V_{INB} = V_{CCB}$ or GND		1.1 to 1.4	1.65 to 2.3	_	2.0	
	I _{CCA}	$V_{CCA} \leq (V_{IN}, V_{OUT}) \leq 3.6$ \	/	1.1 to 1.4	1.65 to 2.3		±2.0	
	I _{CCB}	$V_{CCB} \le (V_{IN}, V_{OUT}) \le 3.6$ \	/	1.1 to 1.4	1.65 to 2.3	_	±2.0	

12.2. AC Characteristics

12.2.1. V_{CCA} = 2.5 ± 0.2 V, V_{CCB} = 3.3 ± 0.3 V (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 2.0 ns)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	5.4	ns
3-state output enable time ($\overline{OE} \rightarrow An$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	8.4	
3-state output disable time ($\overline{OE} \rightarrow An$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	6.7	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	6.8	ns
3-state output enable time ($\overline{OE} \rightarrow Bn$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	8.7	
3-state output disable time ($\overline{\text{OE}} \rightarrow \text{Bn}$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	3.9	
Output skew	t _{osLH} /t _{osHL}	(Note 1)		_	0.5	ns

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

12.2.2. $V_{CCA} = 1.8 \pm 0.15$ V, $V_{CCB} = 3.3 \pm 0.3$ V (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 2.0$ ns)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	8.9	ns
3-state output enable time ($\overline{OE} \rightarrow An$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	13.4	
3-state output disable time ($\overline{\text{OE}} \rightarrow \text{An}$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	10.9	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	7.8	ns
3-state output enable time ($\overline{OE} \rightarrow Bn$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	10.7	
3-state output disable time ($\overline{\text{OE}} \rightarrow \text{Bn}$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	5.2	
Output skew	t _{osLH} /t _{osHL}	(Note 1)		_	0.5	ns

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

12.2.3. V_{CCA} = 1.5 ± 0.1 V, V_{CCB} = 3.3 ± 0.3 V (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 2.0 ns)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	10.3	ns
3-state output enable time ($\overline{OE} \rightarrow An$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	18.5	
3-state output disable time ($\overline{\text{OE}} \rightarrow \text{An}$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	13.0	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	8.6	ns
3-state output enable time ($\overline{OE} \rightarrow Bn$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	14.3	
3-state output disable time ($\overline{\text{OE}} \rightarrow \text{Bn}$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	6.6	
Output skew	t _{osLH} /t _{osHL}	(Note 1)		_	1.5	ns

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

12.2.4. $V_{CCA} = 1.2 \pm 0.1 \text{ V}$, $V_{CCB} = 3.3 \pm 0.3 \text{ V}$ (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 2.0 \text{ ns}$)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	61	ns
3-state output enable time ($\overline{OE} \rightarrow An$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	95	
3-state output disable time ($\overline{\text{OE}} \rightarrow \text{An}$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	44	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	22	ns
3-state output enable time ($\overline{OE} \rightarrow Bn$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	52	
3-state output disable time ($\overline{OE} \rightarrow Bn$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	18	
Output skew	t _{osLH} /t _{osHL}	(Note 1)		_	1.5	ns

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

12.2.5. $V_{CCA} = 1.8 \pm 0.15 \text{ V}, V_{CCB} = 2.5 \pm 0.2 \text{ V}$ (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 2.0 \text{ ns}$)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	9.1	ns
3-state output enable time ($\overline{OE} \rightarrow An$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	13.5	
3-state output disable time ($\overline{OE} \rightarrow An$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	11.8	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	9.5	ns
3-state output enable time ($\overline{OE} \rightarrow Bn$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	12.6	
3-state output disable time ($\overline{OE} \rightarrow Bn$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	5.1	
Output skew	t _{osLH} /t _{osHL}	(Note 1)			0.5	ns

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

12.2.6. V_{CCA} = 1.5 ± 0.1 V, V_{CCB} = 2.5 ± 0.2 V (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 2.0 ns)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	10.8	ns
3-state output enable time ($\overline{OE} \rightarrow An$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	18.3	
3-state output disable time ($\overline{OE} \rightarrow An$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	14.2	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	10.5	ns
3-state output enable time ($\overline{OE} \rightarrow Bn$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	15.4	
3-state output disable time ($\overline{OE} \rightarrow Bn$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	6.4	
Output skew	t _{osLH} /t _{osHL}	(Note 1)		_	1.5	ns

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

12.2.7. $V_{CCA} = 1.2 \pm 0.1 \text{ V}$, $V_{CCB} = 2.5 \pm 0.2 \text{ V}$ (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 2.0 \text{ ns}$)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	60	ns
3-state output enable time ($\overline{OE} \rightarrow An$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	95	
3-state output disable time ($\overline{\text{OE}} \rightarrow \text{An}$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	45	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	23	ns
3-state output enable time ($\overline{OE} \rightarrow Bn$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	54	
3-state output disable time ($\overline{OE} \rightarrow Bn$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	17	
Output skew	t _{osLH} /t _{osHL}	(Note 1)		_	1.5	ns

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

12.2.8. $V_{CCA} = 1.2 \pm 0.1 \text{ V}$, $V_{CCB} = 1.8 \pm 0.15 \text{ V}$ (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 2.0 \text{ ns}$)

Characteristics	Symbol	Note	Test Condition	Min	Max	Unit
Propagation delay time (Bn \rightarrow An)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	58	ns
3-state output enable time ($\overline{\text{OE}} \rightarrow \text{An}$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	92	
3-state output disable time ($\overline{OE} \rightarrow An$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	47	
Propagation delay time (An \rightarrow Bn)	t _{PLH} /t _{PHL}		See Fig. 13.1, 14.1 Table 13.1.1, 13.1.2, 14.1.1	1.0	30	ns
3-state output enable time ($\overline{\text{OE}} \rightarrow \text{Bn}$)	t _{PZL} /t _{PZH}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	55	
3-state output disable time ($\overline{OE} \rightarrow Bn$)	t _{PLZ} /t _{PHZ}		See Fig. 13.1, 14.2 Table 13.1.1, 13.1.2, 14.1.1	1.0	17	
Output skew	t _{osLH} /t _{osHL}	(Note 1)		_	1.5	ns

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

12.3. Dynamic Switching Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics		Symbol	Note	Test Condition	V _{CCA} (V)	V _{CCB} (V)	Тур.	Unit
Quiet output maximum dynamic	$A \rightarrow B$	V _{OLP}	(Note 1)	V _{IH} = V _{CC} , V _{IL} = 0 V	2.5	3.3	0.8	V
V _{OL}					1.8	3.3	0.8	
					1.8	2.5	0.6	
	$B \rightarrow A$	1			2.5	3.3	0.6	
					1.8	3.3	0.25	
					1.8	2.5	0.25	
Quiet output minimum dynamic	$A \rightarrow B$	V _{OLV}	(Note 1)	$V_{IH} = V_{CC}, V_{IL} = 0 V$	2.5	3.3	-0.8	V
V _{OL}					1.8	3.3	-0.8	
					1.8	2.5	-0.6	
	$B \rightarrow A$	1			2.5	3.3	-0.6	
					1.8	3.3	-0.25	
					1.8	2.5	-0.25	
Quiet output maximum dynamic	$A \rightarrow B$	V _{OHP}	(Note 1)	$V_{IH} = V_{CC}, V_{IL} = 0 V$	2.5	3.3	4.6	V
V _{OH}					1.8	3.3	4.6	
					1.8	2.5	3.3	
	$B \rightarrow A$				2.5	3.3	3.3	
					1.8	3.3	2.3	
					1.8	2.5	2.3	
Quiet output minimum dynamic	$A \rightarrow B$	V _{OHV}	(Note 1)	$V_{IH} = V_{CC}, V_{IL} = 0 V$	2.5	3.3	2.0	V
V _{OH}					1.8	3.3	2.0	
					1.8	2.5	1.7	
	$B \rightarrow A$				2.5	3.3	1.7	
					1.8	3.3	1.3	
					1.8	2.5	1.3	

Note 1: Parameter guaranteed by design.

12.4. Capacitive Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note		Test Condition	V _{CCA} (V)	V _{CCB} (V)	Тур.	Unit
Input capacitance	C _{IN}		DIR, OE		2.5	3.3	7	pF
Bus I/O capacitance	C _{I/O}		An, Bn		2.5	3.3	8	pF
Power dissipation	C _{PDA}	(Note 1)	OE = L	$A \rightarrow B (DIR = H)$	2.5	3.3	3	pF
capacitance				$B \rightarrow A (DIR = L)$	2.5	3.3	16	
			OE = H	$A \rightarrow B (DIR = H)$	2.5	3.3	0	
				$B \rightarrow A (DIR = L)$	2.5	3.3	0	
	C _{PDB}	(Note 1)	OE = L	$A \rightarrow B (DIR = H)$	2.5	3.3	16	
				$B \rightarrow A (DIR = L)$	2.5	3.3	5	
			OE = H	$A \rightarrow B (DIR = H)$	2.5	3.3	0	
				$B \rightarrow A (DIR = L)$	2.5	3.3	0	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per bit)

13. AC Test Circuit

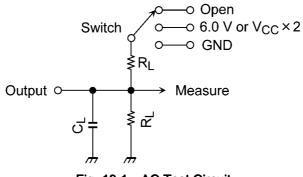




Table 13.1.1 Parameter for AC Test Circuit

Parameter	Switch	Test Condition
t _{PLH} , t _{PHL}	Open	—
t _{PLZ} , t _{PZL}	6.0 V	V_{CC} = 3.3 \pm 0.3 V
	$V_{CC} imes 2$	V_{CC} = 2.5 \pm 0.2 V
		V_{CC} = 1.8 \pm 0.15 V
		V_{CC} = 1.5 \pm 0.1 V
		V_{CC} = 1.2 \pm 0.1 V
t _{PHZ} , t _{PZH}	GND	_

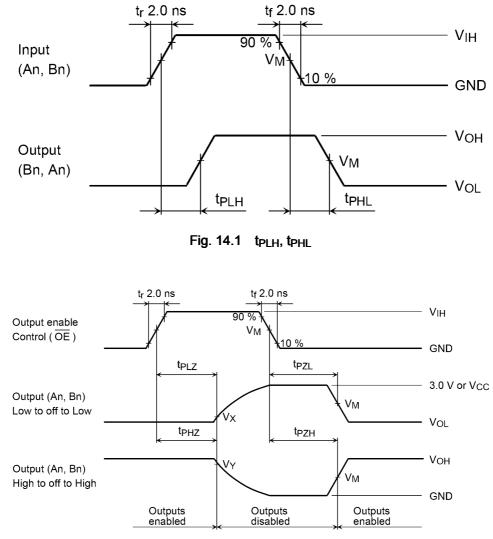
Table 13.1.2 Para	ameter for AC	Test Circuit
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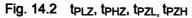
Symbol	$\begin{array}{l} {\sf V}_{\rm CC} = 3.3 \pm 0.3 \; {\sf V} \\ {\sf V}_{\rm CC} = 2.5 \pm 0.2 \; {\sf V} \end{array}$	V_{CC} = 1.8 \pm 0.15 V	V_{CC} = 1.5 \pm 0.1 V	V_{CC} = 1.2 \pm 0.1 V
RL	500 Ω	1 kΩ	2 kΩ	10 kΩ
CL	30 pF	30 pF	15 pF	15 pF

TC7MP3125FK

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14. AC Waveform



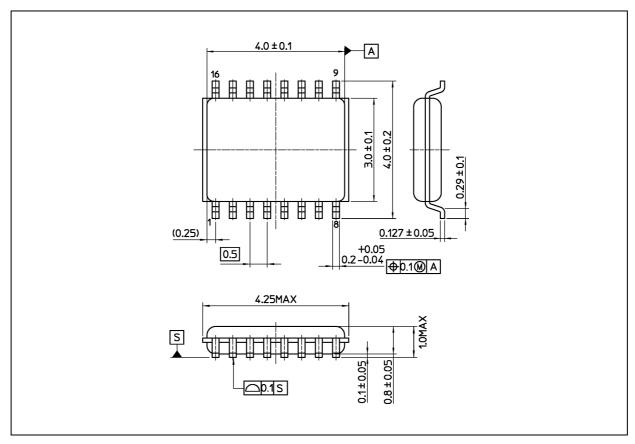


Symbol	V_{CC} = 3.3 \pm 0.3 V	$\begin{array}{c} V_{CC} = 2.5 \pm 0.2 \ V \\ V_{CC} = 1.8 \pm 0.15 \ V \end{array}$	$\begin{array}{l} V_{CC} = 1.5 \pm 0.1 \ V \\ V_{CC} = 1.2 \pm 0.1 \ V \end{array}$
V _{IH}	2.7 V	V _{CC}	V _{CC}
V _M	1.5 V	V _{CC} /2	V _{CC} /2
V _X	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.1 V
V _Y	V _{OH} - 0.3 V	V _{OH} - 0.15 V	V _{OH} - 0.1 V

TC7MP3125FK

Package Dimensions

Unit: mm



Weight: 0.02 g (typ.)

	Package Name(s)
Nickname: US16	

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